

TOSHIBA Transistor Silicon NPN Triple Diffused Planar Type

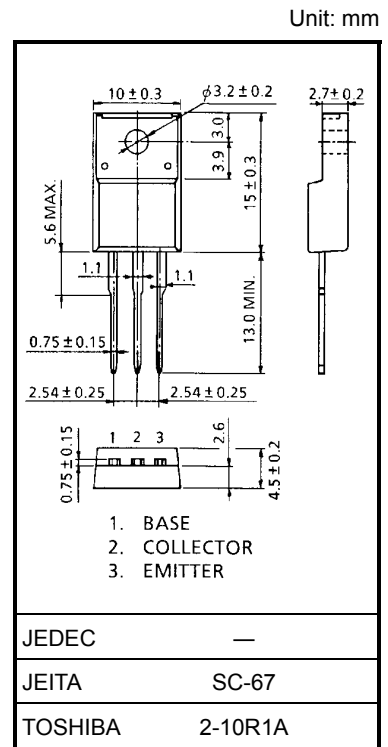
# 2SC4686, 2SC4686A

TV Dynamic Focus Applications  
 High-Voltage Switching Applications  
 High-Voltage Amplifier Applications

- High voltage:  $V_{CEO} = 1200\text{ V (max)}$
- Small collector output capacitance:  $C_{ob} = 2.2\text{ pF (typ.)}$  ( $V_{CB} = 100\text{ V}$ )

### Absolute Maximum Ratings ( $T_c = 25^\circ\text{C}$ )

Characteristics	Symbol	Rating	Unit
Collector-base voltage	$V_{CBO}$	1500	V
Collector-emitter voltage	$V_{CEO}$	1000	V
		1200	
Emitter-base voltage	$V_{EBO}$	5	V
Collector current	DC	$I_C$	mA
	Pulse	$I_{CP}$	
Base current	$I_B$	25	mA
Collector power dissipation	$P_C$	$T_c = 25^\circ\text{C}$	W
		$T_a = 25^\circ\text{C}$	
Junction temperature	$T_j$	150	$^\circ\text{C}$
Storage temperature range	$T_{stg}$	-55 to 150	$^\circ\text{C}$



Weight: 1.7 g (typ.)

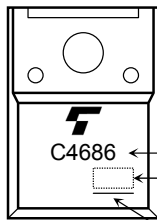
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

## Electrical Characteristics (Tc = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	$I_{CBO}$	$V_{CB} = 1200\text{ V}, I_E = 0$	—	—	1.0	$\mu\text{A}$
Emitter cut-off current	$I_{EBO}$	$V_{EB} = 5\text{ V}, I_C = 0$	—	—	10	$\mu\text{A}$
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C = 100\ \mu\text{A}, I_E = 0$	1500	—	—	V
Collector-emitter breakdown voltage	2SC4686	$V_{(BR)CEO}$ $I_C = 1\text{ mA}, I_B = 0$	1000	—	—	V
	2SC4686A		1200	—	—	
DC current gain	$h_{FE}$	$V_{CE} = 5\text{ V}, I_C = 3\text{ mA}$	15	—	60	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 10\text{ mA}, I_B = 2\text{ mA}$	—	0.16	1.5	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C = 10\text{ mA}, I_B = 2\text{ mA}$	—	0.7	1.5	V
Transition frequency	$f_T$	$V_{CE} = 10\text{ V}, I_C = 3\text{ mA}$	—	5.5	—	MHz
Collector output capacitance	$C_{ob}$	$V_{CB} = 100\text{ V}, f = 1\text{ MHz}, I_E = 0$	—	2.2	—	pF

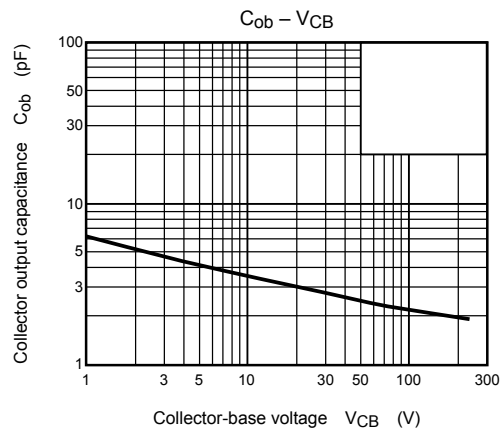
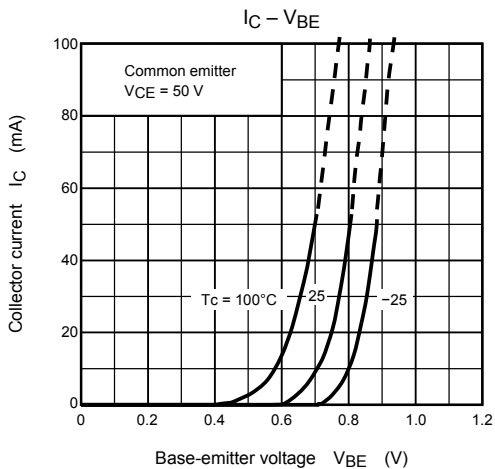
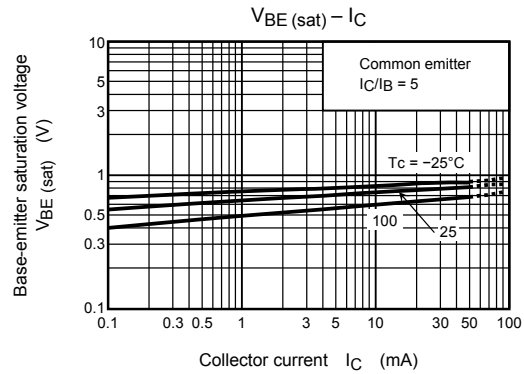
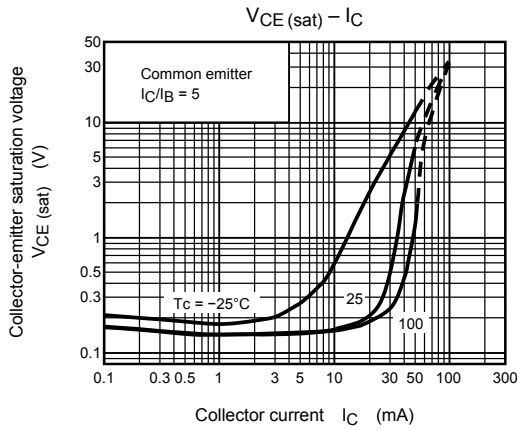
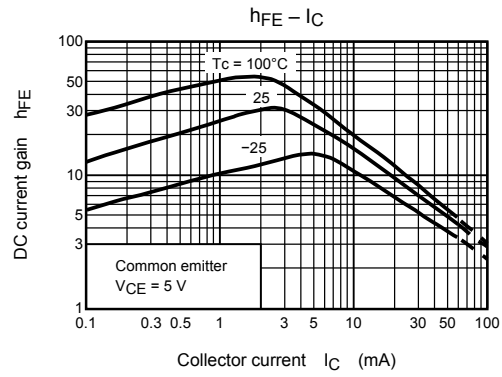
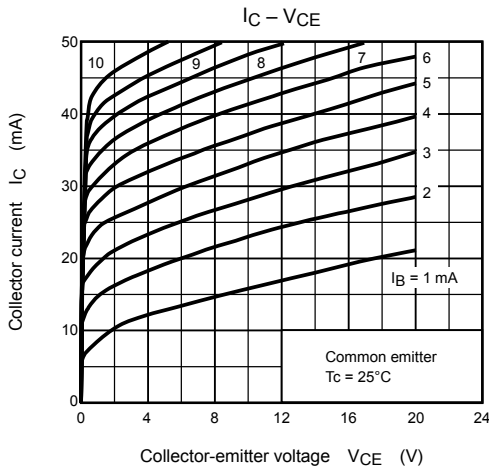
## Marking

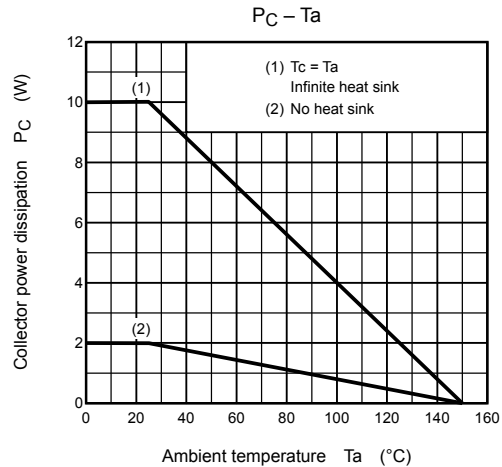
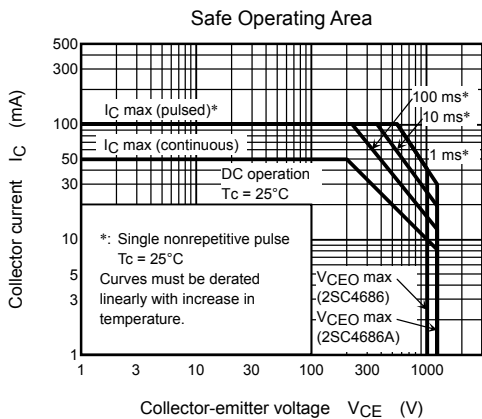
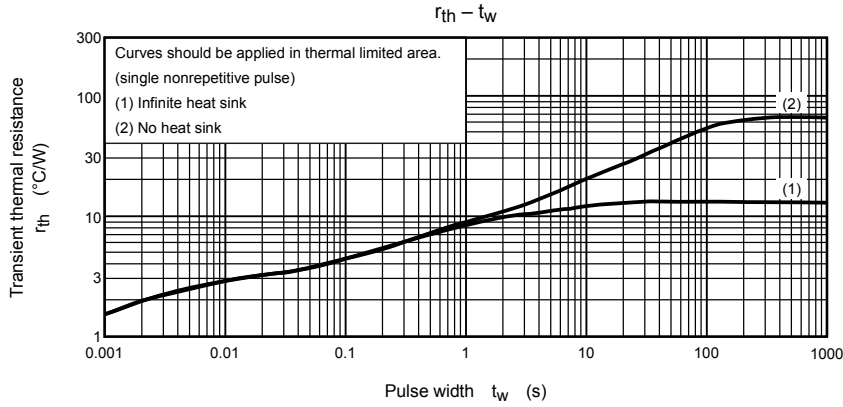
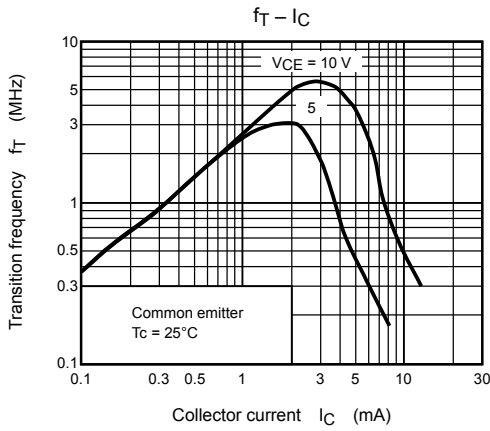


C4686 ← Part No. (or abbreviation code) \*1  
 [ ] ← Lot No.

A line indicates lead (Pb)-free package or lead (Pb)-free finish.

*1	Part No. (or abbreviation code)	Part No.
	C4686	2SC4686
	C4686A	2SC4686A





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20070701-EN

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